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Excess PbI₂ in perovskite film is an effective strategy for boosting perovskite solar cells (PSCs) performance. However, the presence of unreacted PbI₂ is a critical source of intrinsic instability in perovskite under illumination, due to the photolysis of PbI₂ (decomposed into metallic lead and iodine). Herein, this issue is solved by applying ionic liquids (ILs) on PSCs where the ILs can form types of stable supramolecules with residual lead iodide. The formation process and mechanism of the supramolecules are elucidated. The residual PbI₂ is also revealed to cause high level lead interstitial defects and induced tensile strain which further deteriorate device performance. The self-assembled supramolecular complex can passivate the PSCs where significant enhancements are achieved in both power conversion efficiency (PCE, from 21.9% to 23.4%) and device stability (retaining 95% of the initial PCE after 4080 h in ambient dry-air storage, and 80% after 1400 h continuous light illumination).

1. Introduction

Metal halide perovskite solar cells (PSCs) have achieved certified power conversion efficiency (PCE) of 25.5% within just a decade of amazing progress.^[1-3] Among the various strategies adopted, the addition of excess PbI₂ (5-10 mol%) in the precursor of PSCs is a very popular strategy for efficiency enhancement (10 mol% excess PbI_2 was used in the first >25% PSC).^[1] Unreacted PbI₂ is reported to be located at the grain boundaries, the perovskite grain surface, and the interface between the perovskite and transporting layer.^[4–13] The benefits of excess PbI_2 in PCE have been widely investigated and was attributed to the mechanisms such

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as passivating the defects at grain boundaries, preventing the formation of organic-rich surface, reducing halide vacancy concentration, and enhancing the charge transport.^[4–10] The unreacted PbI₂ formed at the interface between the perovskite layer and charge transport layer can effectively suppress carrier recombination and facilitate the carrier injection.^[5,11,12] However, the presence of unreacted PbI₂ is a double-edged sword for the PSCs,^[14] which is a critical source of intrinsic instability in perovskite under illumination, due to the photolysis of PbI₂ (decomposed into metallic lead and iodine).^[10,15–18] It is not enough to pursue high efficiency by sacrificing the device stability with the strategy of excess PbI₂.^[15,17]

Several methods have been introduced to eliminate the detrimental effect of unreacted PbI₂. Wang et al. reported a ligandmodulation technique, in which the shape and distribution of excess PbI₂ in the perovskite films were modulated from the random distribution of excess PbI₂ into vertically distributed PbI₂ nanosheets.^[19] While it benefits the device performance, this distribution regulation of unreacted PbI₂ cannot change the nature of instability induced by the photolysis of PbI₂. Secondary growth method by employing organic cations (MAI, MABr, FAI, GuaBr, et al.)/isopropyl alcohol (IPA) solution surface treatment is an effective way to eliminate the residual PbI₂ by converting it to perovskite, whose stability needs further boosting.^[20–23] Therefore, efforts are required to simultaneously remove the residual PbI₂ and improve stability.

Ionic liquids (ILs) with unique advantages have been applied in PSCs to play multiple functions for efficient and stable PSCs, including film formation dynamics control, interface modification, chemical passivation, stability improvement, and innovative alternatives to traditional materials.^[24,25] However, it is still unclear the distribution of ILs in the perovskite films, and the interaction between ILs and residual PbI₂. Noticed ILs are easily interacted with lead halides and form organic-inorganic plumbate with supramolecular organizations (here, we adopt the term supramolecule from previous literature and used in the following section.).^[26-32] The self-assembly supramolecules exhibit promising semiconducting property, structural rigidity, and excellent stability.^[27,30-34] Thus, the ultra-stable supramolecule formed from ILs and PbI₂ holds the promise to simultaneously remove the residual PbI₂ and realize stable PSCs, and provides evidence to track the distribution of ILs in perovskite film.

In this work, we used the 1-butyl-3-methylimidazoliumbased ILs ([BMIM]X) to react with excess PbI₂ in perovskite film and form the self-assembly supramolecule complex [BMIM]Pb₂X₅, which is extremely stable under continuous light illumination in the ambient environment, thus efficiently eliminates the detrimental stability effect of unreacted PbI₂. This novel IL-based multimode supramolecular complex engineering (ILSC) approach is shown universal in boosting device PCE by passivating Pb interstitial defects across various PSC material systems: (FAPbI₃)_{0.95}(MAPbBr₃)_{0.05} perovskite (FAMA) and (FAPbI₃)_{0.93} (MAPbI₃)_{0.04}(CsPbI₃)_{0.03} perovskite (FAMACs) as example here). The FAMACs PSC with the ILSC approach ([BMIM]Br) exhibits a PCE of 23.4% (vs the control device of 21.9%). The PCE of FAMA PSCs was enhanced from 19.49% (control device) to 21.94% ([BMIM]Br-treated device) and 22.33% ([BMIM]Cl-treated device). Moreover, perovskite films with excess PbI2 were observed to have larger tensile strain than perovskite film with stoichiometric PbI₂, which can be effectively released through ILSC approach by curing the Pb²⁺ interstitial induced lattice distortion and eliminating the thermal expansion coefficient mismatch between perovskite and lead iodide. Through the synergetic regulations on both the detrimental excess PbI₂ and residual tensile strain, the ILSC approach enables high-stability PSCs: maintaining 95% of the initial PCE after 4080 h ambient storage in dry box and 80% of PCE after 1400 h under light illumination.

2. Results and Discussion

2.1. Mechanism of IL on Excess PbI₂ Management

In high-efficiency PSCs, excess PbI₂ (here 10%) is commonly applied as a defect passivation agent in the perovskite film.^[1] However, the excess PbI₂ is also shown to increase the ionic movement and photodecomposition, deteriorating the stability of the perovskite layer.^[10,14,35] To modulate the excess PbI₂ and enhance the efficiency and stability of PSCs, 1-butyl-3-methylimidazolium-based ILs ([BMIM]X) are utilized to form supramolecular organizations with PbI₂.^[26-29] As illustrated in Figure 1a, [BMIM]Br/IPA solution is coated on (FAPbI₃)_{0.95}(MAPbBr₃)_{0.05} perovskite films, then the sample is annealed at 100 °C for 10 min to form supramolecular organization. The supramolecule is first demonstrated by X-ray diffraction (XRD) results (Figure 1b), that new peaks appear except the dominant peaks of α -FAPbI₃ ((100) at 13.95°, (111) at 24.45°, (200) at 28°), δ -FAPbI₃ (11.7°), and the PbI₂ peak (12.6°). The new peak at 7.9° is generated with a low concentration of [BMIM] Br (1 and 3 mg mL⁻¹), which is attributed to Supramolecule I (confirmed as the supramolecular organization of MPb₂X₅ in the following section, where M stands for the organic cation and X represents the halide anion). When the concentration of [BMIM]Br increases to 5 mg mL⁻¹, a new peak at around 10° arises, suggesting another compound (Supramolecule II, also confirmed as the supramolecular organization of MPbX₃ in the following section) is formed. Continuously increasing [BMIM] Br to 10 mg mL⁻¹, the peak at 7.9° completely disappears and only the peak at 10.0° remains. These XRD results declare new compounds formed and a clear phase transformation with the increase of [BMIM]Br concentration. This phenomenon is also observed for the [BMIM]Cl-treated films (Figure S1a, Supporting Information), suggesting that the [BMIM]⁺ plays a critical role in the reaction. Moreover, both peak intensities for PbI₂ and δ -FAPbI₃ are reduced for [BMIM]Br-treated case, compared with the control film, indicating that the [BMIM]Br can effectively suppress the formation of nonperovskite δ -phase FAPbI₃ by forming new phases.

Specifically, perovskite films with different PbI₂:FAI ratios are prepared and treated with 3 mg mL⁻¹ [BMIM]Br. The XRD patterns (Figure 1c) demonstrate that a clear new peak of Supramolecule I at 7.9° is observed in the film with PbI₂:FAI ratio of 1.2:1, while there are almost no emerging peaks for 1:1 and 0.9:1 ratios of PbI₂:FAI, indicating the supramolecule could only form with the residual PbI₂.

Confirmed by the grazing-incidence wide-angle X-ray scattering (GIWAXS) results (Figure 1e), after treated with







Figure 1. Mechanism of IL on excess Pbl₂ management. a) Schematic illustration of supramolecule formation on perovskite film—supramolecule perovskite (s-perovskite). b) XRD patterns of formation of perovskite with different concentrations of IL. c) XRD patterns of 3 mg mL⁻¹ [BMIM]Br-treated perovskite film with Pbl₂:FAI ratio of 1.2:1, 1:1, and 0.9:1. d) XRD patterns of 3 mg mL⁻¹ [BMIM]Br-modulated perovskite films with and without annealing process. e) GIWAXS patterns of the control and perovskite films for different concentrations IL. f) Top-view and cross-sectional view SEM images of control and perovskite films with Supramolecule I (3 mg mL⁻¹) and Supramolecule II (5 mg mL⁻¹).

[BMIM]Br, the typical perovskite phase ((100) at *q* of 1.0 Å⁻¹) remains unchanged, while the PbI₂ phase (*q* of 0.9 Å⁻¹) gradually diminishes and new phases of *q* = 0.56 and 0.68 Å⁻¹ generate, suggesting interaction between PbI₂ and [BMIM]Br. At low [BMIM]Br concentrations (1 and 3 mg mL⁻¹), new peak appears at *q* = 0.56 Å⁻¹ (2 θ peak position at 7.9°, Supramolecule I), while with the increases of [BMIM]Br concentration, Supramolecule I transforms into a new phase at 0.68 Å⁻¹ (2 θ peak position at 10.0°)—Supramolecule II, agreeing well with the XRD results.

Noted that the annealing process is necessary for the generation of supramolecular organization, as only the annealed film exhibits new XRD diffraction peaks (Figure 1d). The optical images (Figure S1b, Supporting Information) show that the color of [BMIM]Br-treated perovskite films (light gold color for 3 mg mL⁻¹ [BMIM]Br-treated and light purple color 5 mg mL⁻¹ [BMIM]Br-treated film) changed to the same color as the control one after thermal annealing, indicating the supramolecule formation upon thermal annealing on top of perovskite film, i.e., supramolecule–perovskite heterojunction.





Figure 2. Depth-resolved investigation of excess Pbl₂ through perovskite film. a) Schematic diagram of the proposed three regions of supramolecule and excess Pbl₂ distributed on perovskite film. b) Depth-resolved GIWAXS pattern of control film and s-perovskite. c) ToF-SIMS depth profiles of the s-perovskite film over sputtering time. d) The calculated Pbl₂/PSC (100) ratio from depth-resolved GIWAXS pattern of control film.

Additionally, imidazolium-based ILs with different lengths of alkyl chains were investigated (Figure S2, Supporting Information). The XRD patterns show that compared to [BMIM]Br, 1-methyl-3-propylimidazolium bromide ([MPRIM]Br) and 1-ethyl-3-methylimidazolium bromide ([EMIM]Br) with shorter alkyl chains can only give new peaks at around 10°, while 1-methyl-3-pentylimidazolium bromide ([MPEIM]Br), 1-hexyl-3-methylimidazolium bromide ([HMIM]Br), and 1-methyl-3-octylimidaolium bromide ([OMIM]Br) with longer alkyl chains only exhibit new peaks at around 7.9°.

As shown in top-view scanning electron microscope (SEM) images (Figure 1f), the unreacted PbI₂ in the forms of brighter nanocluster is randomly distributed in the control perovskite film, which is consistent with the previous reports.^[17] After treated with [BMIM]Br, instead of residual PbI2, new features locating between the perovskite grain boundaries are observed, and the perovskite grain size becomes larger, which may be attribute to the Ostwald ripening.^[36] The grain size distribution is shown in Figure S3 in the Supporting Information. The average grain size of control film is around 0.72 µm. The perovskite grain size becomes larger after treatment with [BMIM]Br where the average grain size of film with Supramolecule I is 0.87 μ m. The enlarged grain size can be confirmed by the XRD results in Figure 1b, that the full-width at half-maximum (FWHM) of the (100) diffraction peak for 3 mg mL⁻¹ and 5 mg mL⁻¹ [BMIM] Br-treated films are 0.211 and 0.234, respectively, lower than the control film of 0.243. According to the Scherrer's equation, the reduced FWHM reflects enlarged crystallize size for [BMIM]Brtreated films. The treatment of [BMIM]Br also reduces the film roughness to 18.8 nm, where the surface roughness of control film is 34.9 nm (Figure S4, Supporting Information).

2.2. Depth-Resolved Investigation of Excess Pbl_2 over the Perovskite Film

As the perovskite film is treated with IL from the top surface, it is necessary to investigate the content of residual PbI_2 over

the whole perovskite film (Figure 2a). Depth-resolved GIWAXS measurements are first used to probe the unreacted PbI₂ content at a specific depth via changing the incident angle. Three incident angles of 0.1°, 0.3°, and 1° are selected for the top 10 nm, the middle layer of film, and the whole film of GIWAXS test, respectively.^[23] For the control perovskite film (Figure 2b), a strong PbI₂ signal at q = 0.9 Å⁻¹ is observed for all three incident angles, suggesting the residual PbI₂ across the whole film. In contrast, no PbI₂ signal is detected near the film surface (0.1°) for the [BMIM]Br-treated films, and only a very weak peak of the PbI₂ phase is observed at higher incident angles of 0.3° and 1.0°. In comparison, the [BMIM]Br-treated films exhibit a strong peak at q = 0.56 Å⁻¹ (Supramolecule I) regardless of incident angles, indicating that most of the excess PbI₂ was converted. Furthermore, the ratios of PbI₂ and perovskite (100) peak intensity from the depth-resolved GIWAXS results are calculated for the control film (Figure 2d) to investigate the PbI₂ distribution throughout the perovskite film. The ratio is two times higher in the middle layer than those in the top and bottom layers, declaring a higher content of PbI₂ in the middle of the perovskite film.

The Fourier-transform infrared spectroscopy (FTIR) and time-of-flight secondary-ion mass spectrometry (ToF-SIMS) measurement are conducted to further investigate the presence of [BMIM]Br and distribution of chemical composition throughout the ILSC perovskite films. The IR spectrum (Figure S5, Supporting Information) of [BMIM]Br shows the characteristic IR modes at 590-690, 1080-1600, and 2800–3200 cm⁻¹ (alkyl and imidazole ring C–H stretch), which is consistent with the reported by Rao and Rajkumar.^[37] A closer examination of IR spectra in the imidazole ring C-H stretch between 3000 and 3250 cm⁻¹ shows that compared to the control perovskite film, new vibrations at 3112, 3165, and 3199 cm⁻¹ are seen for [BMIM]Br-treated case, confirmed the presence of [BMIM]Br in the perovskite film. From the ToF-SIMS, the abrupt boosting of the F⁻ signal indicates the touching of the fluorine-doped tin oxide (FTO) substrate after 275 s ion sputtering (Figure 2c).



Figure 3. The supramolecules formation via IL on PbI_2 management. IL-based supramolecular organization: a) Supramolecule I MPb₂X₅ and b) Supramolecule II MPbX₃. Comparison TEM diffraction pattern image of experiment results (left) and simulation (right) of c) Supramolecule I MPb₂X₅ and d) Supramolecule II MPbX₃. GIWAXS patterns of e) Supramolecule I and f) Supramolecule II. g) XRD patterns of two types of supramolecule. h) XRD of fresh and aged Supramolecule I under continuous light illumination. M represents the imidazolium cation, and X is the halogen anion.

The composition of MA⁺ is linear increase at the first 47 s ion sputtering and become constant after 47 s. This indicates less MA⁺ is distributed at the top surface of perovskite film. which could be attributed to the evaporation of MA during annealing process. The MA⁺ at the top surface is much easier released than the MA⁺ at the middle or bottom layer of perovskite film. The compositions of FA⁺ and Pb²⁺ are almost constant over the whole perovskite film, while there exist three regions of [BMIM]⁺ throughout the film: I) Initial/top drop region; II) accumulation region; and III) final/bottom drop region (Figure 2a,c). Physically, the [BMIM]Br is first coated onto the surface of the perovskite film and then diffuses into the bulk of the film. According to the typical diffusion process, the first linear drop (before 47 s, mainly on the film surface) and the final/bottom drop (III, after 150 s) regions are easy to understand. The existence of accumulation region (II. 47–150 s) is however very interesting since the [BMIM]⁺ is abnormally increasing and accumulated in the middle of the film. The distribution of unreacted PbI₂ in the film, as confirmed by the depth-resolved GIWAXS analysis (Figure 2d), may provide insight in understanding the abnormal [BMIM]+ distribution. If the [BMIM]Br reacts with PbI₂, the accumulation of PbI₂ will result in the accumulation of [BMIM]⁺ in the middle of perovskite film. In this scenario, the [BMIM]⁺ can track the unreacted PbI₂ and the ILSC is a powerful approach to eliminate the unreacted PbI₂ not only on the surface but also in the bulk of perovskite film.

2.3. Formation of Supramolecule via IL and the Density Functional Theory (DFT) Calculation

To understand the mechanism and figure out the structures of two Supramolecules I and II, films were made by spin-coating with different ratios of PbI₂ and [BMIM]Br. As the XRD results shown in **Figure 3**g, two main peaks located at 7.9° and 10° are found for the films of Supramolecule I ([BMIM]Pb₂I₄Br, PbI₂:[BMIM]Br = 2:1) and Supramolecule II ([BMIM]PbI₂Br, PbI₂:[BMIM]Br = 1:1), respectively, exactly the same with the peaks of Supramolecule on perovskite film shown in Figure 1b. The corresponding GIWAXS (Figure 3e,f) shows clear bright Bragg spots around *q* of 0.56 and 0.68 Å⁻¹ for the Supramolecules I and II, respectively, representing the detailed crystallographic information of Supramolecule I and II in the films. These results demonstrated that Supramolecule I and II are the reaction products of [BMIM]Br and PbI₂.

The structures of Supramolecule I and II are then investigated through the single-crystal transmission electron microscope (TEM) measurement. Based on the previous reference on IL-based supramolecule, we propose the structures of two supramolecules in Figure 3a,b.^[27,33] To confirm, we further compare the experimental TEM diffraction figure (left) of the singlecrystal supramolecules with the simulated TEM diffraction figure (right) of the proposed structures (Figure 3c,d). The obtained experimental TEM diffraction patterns match the proposed structures exactly. Therefore, we confirm the proposed



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Figure 4. DFT calculation of Supramolecule I (MPb_2X_5): a) the band structure, b) the PDOS and TDOS, c) charge density of highest occupied band (HOMO) and d) charge density of lowest unoccupied band (LUMO).

structures as: Supramolecule I ([BMIM]Pb₂I₄Br) comprises sheets of corner and edge sharing lead iodide octahedra, separated by [BMIM]⁺ cations which form stacks perpendicular to the anionic slabs; the Supramolecule II ([BMIM]PbI₂Br) consists of one Pb²⁺ and one [BMIM] ⁺ organic cation, where the 1D Pb-I(Br)-Pb chain is formed as inorganic skeleton surrounded by the [BMIM]⁺ cations.

Combined with the XRD results of perovskite films from IL with different alkyl chain lengths, the basic rules of supramolecular organization formation are proposed (Figure S6, Supporting Information). For the imidazolium cations with longer alkyl chains, it tends to self-assemble into MPb₂X₅ Supramolecule I with lead halides. While for the imidazolium cations with shorter alkyl chains, Supramolecule II MPbX₃ is preferably formed during the reaction with lead halides. The connection between alkyl chain length and supramolecular organization structure is possibly linked to the thermodynamic stability of the self-assemble process. During the self-assemble process, the organic cation can be inserted into the space of two parallel Pb-X-Pb chains (or walls). The space between two parallel Pb-X-Pb chains has a range between maximum distance and minimum distance (D_{max} to D_{min}). For the organic cations with different size of (R_{cation}), three conditions exhibit: i) if $2R_{\text{cation}} > D_{\text{max}}$ and $R_{\text{cation}} > D_{\text{min}}$, Supramolecule I will form; ii) if $2R_{\text{cation}} < D_{\text{max}}$ and $R_{\text{cation}} < D_{\text{min}}$, Supramolecule II will form; and iii) if $2R_{\text{cation}} <$ D_{max} and $R_{\text{cation}} > D_{\text{min}}$, both Supramolecule I and II are thermodynamically stable and formation structures are determined by the ratio of organic cation and lead halide. Therefore, the proper alkyl chain length of [BMIM]⁺ results in an interesting concentration-dependent phase transformation from Supramolecule I to II with the reduced PbI₂:[BMIM]X ratio (2:1 to 1:1). The UV-vis absorption spectra are shown in Figure S7a in the Supporting Information, that all the Supramolecules I are at drop stage at 360 nm, while the absorption of Supramolecule II shows an opposite behavior. Besides, at 390 nm, the Supramolecule II drops sharply and Supramolecule I rises. Therefore, we believe this phenomenon is a normal observation.

The reaction between [BMIM]Br and PbI₂ is then studied by X-ray photoelectron spectroscopy (XPS). The typical C 1 s and N 1 s spectra of the control and [BMIM]Br-treated perovskite films (Figure S8, Supporting Information) clearly show a strong C=NH₂⁺ peak corresponding to FA⁺ in perovskites. However, the presence of π - π peak and the intensity of C-NH₂ (\approx 286 eV for C 1 s and ≈401.5 eV for N 1 s) arises in the [BMIM]Br-treated perovskite film and Supramolecule I [BMIM]Pb2I4Br film (Figure S9, Supporting Information), verifying the formation of supramolecules in perovskite film. The XPS core-level energy spectra of Pb 4f for the control perovskite film show two main peaks at 138.79 and 143.73 eV, corresponding to the Pb 4f_{7/2} and Pb $4f_{5/2}$. The shifts of the Pb²⁺ peaks to lower binding energy for [BMIM]Br-treated perovskite films (138.29 and 143.23 eV) and Supramolecule I [BMIM]Pb2I4Br films (138.73 and 143.67 eV) indicate the lowered oxidation state of lead, which is attributed to the formation of [BMIM]Pb₂I₄Br.^[38-40]

Regarding the electronic structures, we apply the DFT to investigate the better device performance of Supramolecule







Figure 5. Photovoltaic and optoelectronic properties of PSCs. FAMA-based PSCs: a) *J*–*V* characterization, b) corresponding EQE spectra, and c) the SPO of the control and [BMIM]Br-treated devices. FAMACs-based PSCs: d) *J*–*V* characterization and e) EQE of the control and [BMIM]Br-treated devices. FAMACs-based PSCs: d) *J*–*V* characterization and e) EQE of the control and [BMIM]Br-treated devices. f) UPS of the control and [BMIM]Br-treated FAMA perovskite films. g) The energy level diagram of the used materials. h) TRPL analysis of perovskite films with [BMIM]Br in different concentrations. i) Stability of the control and [BMIM]Br-treated devices (the statistical data of each condition are collected from five devices).

I-based PSCs. Figure 4a shows a bandgap around 2.14 eV for Supramolecule I, which is close to the experimental results. Notably, the localized empty states next to the conduction band minimum (CBM) are located at Ev + 1.82 eV (EV denotes 0 eV). With the introduction of the empty states, the intrinsically direct bandgap turns into the indirect bandgap due to the change of CBM from Γ point to C after the introduction of ILs. Meanwhile, we also notice the downshifts of valence band maximum (VBM) of 0.32 eV, which is attributed to the compression effect induced by the [BMIM]⁺ layers. Then, the total density of states (TDOS) and partial density of states (PDOS) are demonstrated to reveal the orbital contributions (Figure 4b). For the VBM, it is noted that the I 5p orbitals play the dominant role, where the Pb 6 s orbitals also show a slight contribution. The C 2p orbitals locate at a deep position in the conduction band with an electronic inactive feature, supporting a weak influence on the conductivity. Br 4p orbitals are mostly

located at the lower position of VBM, which mainly comes from the [BMIM]Br. This is potentially induced by the longrange p-p orbital coupling effect between the Br 4p orbitals and Pb 6p orbitals in Supramolecule I. This indicates the introduction of [BMIM]Br layers will influence the electronic structures of perovskite. The empty states induced by the [BMIM]+ layers mainly consist of the N 2p orbitals. Meanwhile, Pb 6p dominates the CBM with minor contributions from I 5p. It is found that C 2p orbitals show an obvious contribution near the CBM, indicating the coupling between the Pb-X-Pb walls and the ILs. Additionally, Figure 4c,d shows the highest occupied molecular orbital (HOMO) and lowest unoccupied molecular orbital (LUMO), respectively, where the HOMO is dominated by Pb-X-Pb walls while the LUMO mainly locates at the [BMIM]⁺ layers. More importantly, the limited overlapping of HOMO and LUMO indicates the limited electronic recombination trend between the holes and electrons, leading to the improved energy conversion efficiency of the solar cells. Therefore, these results confirm that the introduction of IL not only shows an evident interaction with PbI₂ but also demonstrates a significant effect in modulating the electronic structures of the perovskite materials.

2.4. Photovoltaic and Optoelectronic Properties of PSCs

The PSCs are then fabricated with the device configuration of glass/FTO/SnO₂/(FAPbI₃)_{0.95}(MAPbBr₃)_{0.05}/Spiro-OMeTAD/ Au. The detailed experimental information can be found in the Experimental Section. The optimized FAMA-based PSCs are found to be with 3 mg mL⁻¹ [BMIM]Br (Figure S10a and Table S1, Supporting Information), yielding a PCE of 21.94% with a short circuit current (J_{SC}) of 24.8 mA cm⁻², an open-circuit voltage (V_{OC}) of 1.14 V, and an FF of 77.5%. By comparison, the control device shows PCE of 19.5%, $J_{\rm SC}$ of 24.2 mA cm⁻², $V_{\rm OC}$ of 1.08 V, and FF of 74.9%. The forward and reverse-scan results (Figure 5a and Table S2, Supporting Information) indicate a negligible hysteresis for the devices. The external quantum efficiency (EQE) spectra (Figure 5b and Figure S10b, Supporting Information) give the integrated J_{SC} values of 23.5 and 23.6 mA cm⁻² for the control and optimized ILSC devices, respectively, which are in good agreement with the values from I-V curves (within 5% deviation). The steady-state power output (SPO) measurements in 500 s (Figure 5c) present a stable SPO PCE of 19.5% for the control and 21.4% for ILSC PSCs, respectively. Apart from [BMIM]Br, [BMIM]Cl is also used and the general modulation effect through ILSC is further confirmed (Figure S11 and Table S3, Supporting Information). The optimized [BMIM]Cl-treated PSC (3 mg mL⁻¹ [BMIM]Cl), exhibiting a PCE of 22.33%, J_{SC} of 24.8 mA cm⁻², V_{OC} of 1.14 V, and FF of 79.0%, is also on the higher side compared to the control PSCs. The statistic distribution of the photovoltaic parameters (Figure S12, Supporting Information) presents the reproducibility of the $V_{\rm OC}$ and FF enhancement through the ILSC approach. The enhanced V_{OC} and FF of [BMIM]Brmodulated devices (average of 1.126 V and 75.0%) and [BMIM] Cl-based ones (average of 1.13 V and 76.5%) than the control devices (average of 1.09 V and 74.5%) result in the improved average PCE for the ILSC devices ([BMIM]Br of 20.5%, [BMIM] Cl of 21.0% vs control of 19.6%).

To figure out its applicability on another perovskite system, the FA dominant system— $FA_{0.93}MA_{0.04}Cs_{0.03}\mbox{-}based$ PSCs is prepared with ILSC approach (Figure 5d and Table S4, Supporting Information). The control device shows the PCE of 21.7%, J_{SC} of 24.3 mA cm⁻², V_{OC} of 1.17 V, and FF of 76.9%. With the addition of Cs, the control device of FAMACs system exhibited an enhanced $V_{\rm oc}$ from 1.08 to 1.17 over the FAMA system PSCs. The incorporation of Cs in FAPbI₃ can greatly reduce the Gibbs free energy thereby stabilizing the perovskite phase.^[41] Besides a more stable perovskite phase, Cs incorporation could also reduce the impurity phase, enhance photogenerated carrier lifetime, and lowers the density of trap states, leading to an enhancement of PSC's performance.^[42] After ILSC approach, the FAMACs ILSC device exhibits 30 mV V_{OC} enhancement over the control one, affording a PCE of 23.4%, J_{SC} of 24.7 mA cm⁻², V_{OC} of 1.20 V, and FF of 79.0%.

The corresponding EQE of FAMACs ILSC device is around 24.3 mA cm⁻² which is in good agreement with the I_{SC} from I-V curves (within 5% deviation, Figure 5e). Moreover, the ILSC devices based on FAMACs perovskite using IL with different alky chains in cation ([EMIM]Br, [MPRIM]Br, [MPEIM] Br, [HMIM]Br, and [OMIM]Br) were fabricated. The obtained devices exhibit obvious performance boosting with abovementioned ILs, especially the V_{OC} enhancement (20-30 mV) (Figure S13 and Table S5, Supporting Information). In order to figure out the origin of performance enhancements, we also prepared the perovskite solar cell without post-annealing process. As we mentioned before, the post-annealing process is necessary to form supramolecules (Figure 1d), the supramolecules present in the post-annealed devices, and no supramolecules will form in the devices without post-annealing. Figure S13b,c in the Supporting Information shows that both [BMIM]Br-treated FAMA- and FAMACs-based PSCs with postannealing give obviously improved performances to the ones without post-annealing, demonstrating the positive contribution of supramolecules to the device performance improvement. The slight enhancement for [BMIM]Br-treated PSCs without post-annealing compared to the control cases is also achieved and may attributed to the passivation function.

The ultraviolet photoelectron emission spectroscopy (UPS) technique was applied to investigate the electronic structure of the perovskite film with [BMIM]Br (Figure 5f). The calculated work function (WF) for [BMIM]Br-treated perovskite film decreases to 4.56 eV from 4.83 eV (control case), yielding the HOMO level of 5.50 eV ([BMIM]Br-treated) versus 5.86 eV (control). The WF (3.22 eV) and HOMO (5.61 eV) level of Supramolecule I are calculated from UPS spectra in Figure S7b in the Supporting Information. The corresponding Tauc plots according to the $(\alpha h v)^2$ versus energy (Figure S14a, Supporting Information) give bandgaps (E_{o} 's) of 1.51 and 1.52 eV for the control and [BMIM]Br-modulated films, respectively. Then the LUMO levels are calculated to be 3.98 eV ([BMIM]Br-treated) and 4.35 eV (control). The shifting of HOMO and LUMO level of [BMIM]Br-treated perovskite film could be attributed to the formation of supramolecule-perovskite heterojunction at the interface. As the HOMO level of Spiro-OMeTAD is reported to be \approx 5.22 eV,^[43] the [BMIM]Br treatment case reduces the energy barrier between perovskite and Spiro-OMeTAD (Figure 5g). This energy level shift improves the hole collection and block undesirable electron transfer from the perovskite to the Spiro-OMeTAD, benefiting both V_{OC} and FF.

Furthermore, the dependence of $V_{\rm OC}$ and J_{SC} on the light intensity is examined. The $V_{\rm OC}$ versus light intensity curves (Figure S14b, Supporting Information) state that the $V_{\rm OC}$ is proportional to the logarithm of light intensity, and the slopes are calculated to be 1.60 $k_{\rm B}T/q$ for the control and 1.38 $k_{\rm B}T/q$ for the ILSC PSCs, respectively, where $k_{\rm B}$ is the Boltzmann constant, Tis the absolute temperature in Kelvin, and q is the elementary charge. The decreased slope from the control device to [BMIM] Br-treated devices signifies that [BMIM]Br could effectively suppress the trap-assisted recombination, consistent with the 60 mV $V_{\rm OC}$ enhancement. The $J_{\rm SC}$ versus light intensity curves on a double-logarithmic scale (Figure S14c, Supporting Information) can be fitted according to the relation of $J_{\rm SC} \propto \Phi^{\alpha}$, where Φ corresponds to the light intensity and α to the exponent. The





Figure 6. GIXRD with different instrumental ψ values (10°–50°) for a) control film with stoichiometric ratio Pbl₂, b) control film with excess Pbl₂, and c) [BMIM]Br-modulated films with stoichiometric ratio Pbl₂ and d) [BMIM]Br-modulated films with excess Pbl₂. e) Linear fit of $2\theta \sin^2 \psi$ for the measured films. f) Schematic illustration of interstitial atom (Pb)-induced lattice distortion. g) DFT-calculated defect (Pb interstitial) formation energy as a function of lead chemical potential.

calculated α values are 0.96 for the control and 0.97 for the [BMIM]Br ILSC PSCs, respectively, declaring the reduced bimolecular recombination in ILSC PSCs. The trap density variation of the devices is calculated by the space limited current (SCLC) method. Figure S15 in the Supporting Information shows the trap-filling limited voltage (V_{TFL}) of the control and [BMIM] Br-treated device is 0.23 and 0.17 V, respectively. The corresponding trap density can be calculated using $V_{\text{TFL}} = (qn_{\text{trap}}L2)/(2\varepsilon\varepsilon_0)$, where q is the elementary charge, L is the thickness of the perovskite film (850 nm), ε_0 is the permittivity in vacuum (8.85 × 10¹² F m⁻¹), and ε is the relative dielectric constant of FAPbI₃ (46.9). The trap densities n_{trap} of the control and [BMIM]Br devices are 1.65×10^{15} and 1.22×10^{15} cm⁻³, respectively. The lower trap density for [BMIM]Br-treated film indicates improved film quality and passivation effect.

The charge carrier dynamics of the perovskite films were then studied by time-resolved photoluminescence (TRPL, Figure 5h) and the steady-state photoluminescence (PL, Figure S14d, Supporting Information). The TRPL decay profiles were fitted using a bi-exponential decay model ($Y = A_1 \exp(-t/\tau_1) + A_2 \exp(-t/\tau_2)$) (Table S6, Supporting Information). Compared to the control film, the optimized 3 mg mL⁻¹ [BMIM] Br-treated film shows the longest TRPL decay overall lifetime, and the highest PL intensity with a blue peak shift of ~14 nm, consistent with a reduced density of trap sites in the [BMIM] Br-treated devices.

Stability is at the center of PSC research, and tensile strain has been proposed to be another important perovskite instability source recently.^[44,45] Grazing incident X-ray diffraction (GIXRD) technique with 2θ -sin² ψ method is applied to investigate the strain in the perovskite film (for detailed information, see the Supporting Information). The plane (012) at 31.6° (for the minimal overlap on the high-angle side) is selected for stress analysis by varying ψ from 0° to 50° (Figure 6a–d), and the slopes of the $2\theta \sin^2 \psi$ linear fitting is shown in Figure 6e. For control films with both stoichiometric ratio and excess PbI₂, the scattering peaks gradually shift to the smaller 2θ with the increase of ψ angle, indicating the increase of crystal plane distance $d_{(012)}$ and the tensile stress bearing in these films. The $2\theta \sin^2 \psi$ linear fitting shows a larger slope in the film with excess PbI_2 (-0.033) than the stoichiometric ratio one (-0.015), suggesting the film with excess PbI₂ suffers from severer tensile stress. This could be attributed to several reasons: i) the excess PbI₂ causes a high density of lattice distortion by the Pb interstitial (Figure 6f); ii) the lattice constant mismatch and thermal expansion coefficients difference between PbI₂ $(>8 \times 10^{-5} \text{ K}^{-1})^{[46]}$ and perovskite ($\approx 4 \times 10^{-5} \text{ K}^{-1}$).^[47–49] The DFT calculation of Pb interstitial formation energy (Figure 6g) shows that much lower formation energy of Pb interstitial is required for the excess PbI₂ perovskite (inside the range of circle), indicating the Pb interstitial tends to form in the film with excess PbI₂. Though PSCs with excess PbI₂ obtained higher PCEs, the severer tensile strain caused by excess PbI₂ has an adverse side effect on film stability.

Interestingly, with the ILSC approach, the perovskite films with stoichiometric ratio PbI_2 and with excess PbI_2 both exhibit tensile stress relaxation behavior—the scattering peaks shift toward higher 2θ angle, and the slopes of linear fitted $2\theta \cdot \sin^2 \psi$ change to positive values. These results indicate that [BMIM]Br reacts with the unreacted PbI_2 , forming supramolecules, then regulating the strain during the annealing process. The modulation of PbI_2 by forming a new stable supramolecule efficiently cures the lattice distortion and releases the perovskite residual tensile strain. In the optimized condition, it even produces

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compression strain, and thus greatly enhances the intrinsic perovskite stability, as illustrated in the PSCs stability results below. The relaxed strain is further confirmed by Williamson–Hall analysis (Figure S16, Supporting Information) from the XRD patterns in Figure 1b, as the slope of the fitted line for [BMIM]Br-treated film becomes positive (0.000339) compared to the control case of negative (-0.000156).

Then the stability of perovskite films and PSCs are studied (Figure 5i). The storage-stability test was conducted on the nonencapsulated PSC devices by storing in a dark dry box with 20-30% relative humidity at room temperature. For the storagestability, the performance of both control and ILSC devices exhibited a fluctuating performance that first increased and then decreased. The increasing of devices performance at first several days was due to the boosting of conductivity of lithium salts doped Spiro-OMeTAD during the oxidation process under storage condition.^[50] The ILSC devices maintain 94% of their initial PCE after 4000 h storage, while the control case only retains 72% of PCE. For thermal stability, the devices were placed onto 80 °C hotplate in the N2-filled glove box. The ILSC devices exhibit a much-enhanced thermal stability (81% of its initial PCE) over the control devices (55% of initial PCE) after 1200 h thermal annealing. The light stability results were obtained by exposing the encapsulated devices under a white light-emitting diode array with an equivalent light intensity of 1 sun AM 1.5G in the air. In contrast to the rapid PCE decrease of the control devices, the ILSC PSCs exhibit greatly enhanced light stability, maintaining over 80% of their initial PCE after 1400 h light exposure. The ILSC approach effectively eliminates the lead iodide's photolysis and released the tensile strain by forming a stable [BMIM] Pb₂I₄Br supramolecule, greatly increasing the perovskite light stability. The corresponding stability results on JSC, VOC, and FF can be found in Figure S17 in the Supporting Information.

The significantly improved long-term stability of [BMIM] Br-treated PSCs can be explained by the high stability of the Supramolecule I ([BMIM]Pb₂I₄Br). By keeping the Supramolecule I under continuous light illumination in an ambient environment with high relative humidity of 70%, the XRD results (Figure 3g) of the 14 days aged film exhibit the same peaks as the fresh sample, indicating the excellent stability of [BMIM] Pb₂I₄Br under illumination in a high humidity environment.^[32]

The enhanced hydrophobicity of the [BMIM]Br-treated film further guarantees the improved stability (Figure S18, Supporting Information). The contact angle for the [BMIM]Br-treated film (57.5°) is enhanced over the control case (28.7°), resulting in the maintained dark black color in much longer time for the treated film (over 168 h) than the control one (less than 120 h). A similar phenomenon is seen for the perovskite films covered with Spiro-OMeTAD—the control film shows clear water drop spread with time, while the [BMIM]Br-treated film keeps black color after 144 h without spreading of the water drop spot.

3. Conclusion

A stable supramolecular organization modulating strategy—ILSC is developed to regulate the unreacted PbI₂ in perovskite film, which plays dual beneficial roles—modulating excess PbI₂ and regulating tensile strain. The [BMIM]Br is found to effectively modulate PbI₂

to form a very stable complex of [BMIM]Pb₂I₄Br, enabling the ILSC devices with reduced perovskite film defect density and suppressed recombination, affording device PCE enhanced to 23.4%. Moreover, through the ILSC approach, the excess PbI₂ is greatly reduced where the lead iodide photolysis is effectively eliminated, and the tensile strain is released, leading to significantly enhanced long-term and light stability for the [BMIM]Br PSCs.

Supporting Information

Supporting Information is available from the Wiley Online Library or from the author.

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Conflict of Interest

The authors declare no conflict of interest.

Author Contributions

H.Z. and W.Y. contributed equally to this work. G.L. and J.-S.H. supervised the work. G. L., H.Z., and W.Y conceived the idea, designed the experiments. H.Z. and W.Y. wrote the paper, and G.L. revised the paper. H.Z. carried out the device fabrication and majority device characterization. W.Y. and J.G. carried out the AFM measurement, SCLC and FTIR measurement, and revised the manuscript. C.X. and Y.Z. carried out the TEM measurement and structure analysis of supramolecule. M.Q. and X.L. performed ex situ GIWAXS and analyzed the data. Z.R., K.L., Q.L., J.-M.H., G.Y., H.T.C., Z.C., and W.Y. assisted in the simulation, characterization of SEM, XRD, and optical measurements. Z.W. and J.-M.H. measured the PL. D.S. and C.L. measured the UPS and XPS. Y.Z. and Z.Z. measured contact angles. All authors discussed the results and commented on the manuscript.

Data Availability Statement

The data that support the findings of this study are available from the corresponding author upon reasonable request.

Keywords

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